ABSOLUTE MAXIMUM RATINGS

V+ to GND0.3V to +12V V+ to V- (MAX4691/MAX4692/MAX4693)0.3V to +12V
Voltage into any Terminal (Note 1) (V 0.3V) to (V+ + 0.3V)
Continuous Current into any Terminal ±20mA
Peak Current W_, X_, Y_, Z_ (pulsed at 1ms,
10% duty cycle)±40mA
ESD per Method 3015.7> 2kV

Continuous Power Dissipation ($T_A = +70$ °C)
16-Bump UCSP (derate 8.2mW/°C above +70°C) 659mW
16-Pin QFN (derate 18.5mW/°C above +70°C) 1481mW
16-Pin TQFN (derate 16.9mW/°C above +70°C) 1349mW
Operating Temperature Range40°C to +85°C
Storage Temperature Range65°C to +150°C
Lead Temperature (TQFN, QFN only, soldering, 10s) +300°C
Soldering Temperature (reflow)+260°C

Note 1: Voltages exceeding V+ or V- on any signal terminal are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Single +3V Supply

 $(V+=+2.7V \text{ to } +3.6V, V-=0V, V_{IH}=+1.4V, V_{IL}=+0.4V, T_A=-40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}, \text{ unless otherwise noted.}$ Typical values are at $T_A=+25^{\circ}\text{C}$.) (Notes 2, 3, 4)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V _W , V _X , V _Y , V _Z , V _W _, V _Z _		-40°C to +85°C	0		V+	V
On-Resistance (Note 5)	Ron	$V+ = 2.7V; I_W, I_X, I_Y, I_Z = 1mA$	+25°C		45	70	Ω
On-nesistance (Note 3)	TION	V _W _, V _X _, V _Y _, V _Z _ = 1.5V	-40°C to +85°C			80	32
On-Resistance Match Between Channels	ΔR _{ON}	$V+ = 2.7V$; I_W , I_X , I_Y , $I_Z = 1mA$	+25°C		2	5	Ω
(Notes 5, 6)	AHON	$V_{W_{-}}, V_{X_{-}}, V_{Y_{-}}, V_{Z_{-}} = 1.5V$	-40°C to +85°C			6	22
W_, X_, Y_, Z_ Off-	I _{W_} , I _{X_} , I _{Y_} , I _{Z_}	V+ = 3.6V; V _W , V _X , V _Y , V _Z = 3V, 0.6V; V _W , V _X , V _Y , V _Z = 0.6V, 3V	+25°C	-1		+1	nA
Leakage Current (Note 7)			-40°C to +85°C	-10		+10	
W, X, Y, Z Off-Leakage		+25°C	-2		+2	nA	
Current (Note 7)			-40°C to +85°C	-20		+20	IIA
W, X, Y, Z On-Leakage	lw(on), lx(on),	$V + = 3.6V$, $V \downarrow V$, $V \chi$, $V \gamma$, $V \angle = 0.6V$,	+25°C	-2		+2	nΔ
Current (Note 7)	$ V(ON)\rangle$		-40°C to +85°C	-20		+20	nA

2 /VI/IXI/VI

ELECTRICAL CHARACTERISTICS—Single +3V Supply (continued)

 $(V+=+2.7V \text{ to } +3.6V, V-=0V, V_{IH}=+1.4V, V_{IL}=+0.4V, T_A=-40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}, \text{ unless otherwise noted.}$ Typical values are at $T_A=+25^{\circ}\text{C}$.) (Notes 2, 3, 4)

PARAMETER	SYMBOL	CONDITIONS		TA	MIN	TYP	MAX	UNITS
Input Off-Capacitance	CW_(OFF), CX_(OFF), CY_(OFF), CZ_(OFF)	f = 1MHz, Figure	e 7	+25°C		9		рF
	C _{X(OFF)} ,	£ 40411-	MAX4691			68		
Output Off-Capacitance	Cy(OFF),	f = 1MHz, Figure 7	MAX4692	+25°C		36		рF
	Cz(OFF)	r igaro r	MAX4693			20		
	C _{W(ON)} ,		MAX4691			78		
On-Capacitance	C _X (ON),	f = 1MHz,	MAX4692	+25°C		46		рF
	C _{Y(ON)} , C _{Z(ON)}	Figure 7	MAX4693			30		
DYNAMIC		l	1					
Enable Turn-On Time		V _{W_} , V _{X_} , V _{Y_} , V	/7 = 1.5V:	+25°C		180	300	
(MAX4691/MAX4692/ MAX4693)	ton	$R_L = 300\Omega, C_L =$		-40°C to +85°C			350	ns
Enable Turn-Off Time		V _{W_} , V _{X_} , V _{Y_} , V _{7_} = 1.5V;	+25°C		70	100		
(MAX4691/MAX4692/ MAX4693)	toff	$R_L = 300\Omega, C_L =$		-40°C to +85°C			120	ns
Address Transition Time	t-roans	V _W _, V _X _, V _Y _, V	/ _Z _ = 0V, 1.5V;	+25°C		200	350	no
Address transition time	ttrans	$R_L = 300\Omega$, $C_L =$	= 35pF, Figure 3	-40°C to +85°C			400	ns
Break-Before-Make	t _{BBM}	V _W _, V _X _, V _Y _, \		+25°C	2	90		ns
Dreak-Delore-Make	rBBIN	$R_L = 300\Omega$, $C_L =$	= 35pF, Figure 4	-40°C to +85°C	2			113
Charge Injection	Q	VGEN = 0V; RGEN Figure 5	$N = 0\Omega; C_L = 1nF,$	+25°C		0.1		рС
Off-Isolation (Note 8)	V _{ISO}	f = 0.1MHz, R _L = Figure 6	= 50Ω , $C_L = 5pF$,	+25°C		-70		dB
Crosstalk (Note 9)	VcT	f = 0.1MHz, R _L = Figure 6	= 50Ω , $C_L = 5pF$,	+25°C		-75		dB
DIGITAL I/O								
Input Logic-High	VIH				1.4			V
Input Logic-Low	V _{IL}						0.4	V
Input Leakage Current	liN	V _A , V _B , V _C , V _{EN}	= 0V or V+		-1		+1	μΑ
SUPPLY		T						
Positive Supply Current	+	ì	V_B , V_C , $V_{\overline{EN}} = 0V$	+25°C			0.1	μA
- 11 Supp., Su. Siii	1+	or V+		-40°C to +85°C			1	μΑ



ELECTRICAL CHARACTERISTICS—Single +5V Supply

 $(V+=+4.5V \text{ to } +5.5V, V-=0V, V_{IH}=+2V, V_{IL}=+0.8V, T_A=-40^{\circ}C \text{ to } +85^{\circ}C, \text{ unless otherwise noted.}$ Typical values are at $T_A=+25^{\circ}C.)$ (Notes 2, 3, 4)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
ANALOG SWITCH							1
Analog Signal Range	V _W , V _X , V _Y , V _Z , V _{W_} , V _{X_} , V _{Y_} , V _{Z_}		-40°C to +85°C	0		V+	V
On-Resistance (Note 5)	Ron	$V+ = 4.5V$; I_W , I_X , I_Y , $I_Z = 1mA$;	+25°C		25	35	Ω
CTT Hosiotatioo (Note o)	TION	$V_{W_{-}}, V_{X_{-}}, V_{Y_{-}}, V_{Z_{-}} = 3.5V$	-40°C to +85°C			40	22
On-Resistance Match Between Channels	ΔR _{ON}	$V + = 4.5V$; I_{W} , I_{X} , I_{Y} , $I_{Z} = 1mA$;	+25°C		2	4	Ω
(Notes 5, 6)		V _{W_} , V _{X_} , V _{Y_} , V _{Z_} = 3.5V	-40°C to +85°C			5	
On-Resistance Flatness	RFLAT(ON)	V+ = 4.5V; lw, lx, ly, lz = 1mA; Vw_, Vx_, Vy_, Vz_ = 1V, 2.25V,	+25°C		2	6	Ω
(Note 10)	TIFLAT(ON)	3.5V	-40°C to +85°C			8	32
W_, X_ , Y_, Z_ Off-Leakage	l _{W_} , lχ_,	V+ = 5.5V; V _W , V _X , V _Y , V _Z = 4.5V, 1V_; V _W , V _X , V _Y , V _Z = 1V, 4.5V	+25°C	-1		+1	
Current (Note 7)	ΙΥ_, Ι <u>Ζ</u> _		-40°C to +85°C	-10		+10	nA
W, X, Y, Z Off-Leakage	lw(OFF), lx (OFF), ly(OFF), lz(OFF)	V+ = 5.5V; V _W , V _X , V _Y , V _Z = 4.5V, 1V_; V _W _, V _X _, V _Y _, V _Z _ = 1V, 4.5V	+25°C	-2		+2	^
Current (Note 7)			-40°C to +85°C	-20		+20	nA
W, X, Y, Z On-Leakage	I _{W(ON)} , I _{X(ON)} ,	V+ = 5.5V; V _W , V _X , V _Y , V _Z = 1V, 4.5V_; V _W _, V _X _, V _Y _, V _Z _ = 1V,	+25°C	-2		+2	nA
Current (Note 7)	ly(ON), Iz(ON)	4.5V, or unconnected	-40°C to +85°C	-20		+20	IIA
DYNAMIC	ı						
Enable Turn-On Time	ton	$V_{W_{-}}, V_{X_{-}}, V_{Y_{-}}, V_{Z_{-}} = 3V; R_{L} =$	+25°C		90	130	ns
(MAX4691/MAX4692/MAX4693)	UN	300Ω , $C_L = 35pF$, Figure 2	-40°C to +85°C			150	110
Enable Turn-Off Time	toff	V _W _, V _X _, V _Y _, V _Z _ = 3V; R _L =	+25°C		45	60	ns
(MAX4691/MAX4692/MAX4693)	511	300Ω , $C_L = 35pF$, Figure 2	-40°C to +85°C			70	_
Address Transition Time	ttrans	$V_{W_{-}}, V_{X_{-}}, V_{Y_{-}}, V_{Z_{-}} = 0V, 3V;$ $R_{L} = 300\Omega, C_{L} = 35pF,$ Figure 3	+25°C -40°C to +85°C		100	140 160	ns
		V _{W_} , V _{X_} , V _{Y_} , V _{Z_} = 3V; R _L =	+25°C	2	35		
Break-Before-Make	tBBM	VW_{\perp} , VX_{\perp} , VY_{\perp} , $VZ_{\perp} = 3V$, $YY_{\perp} = 300\Omega$, $YY_{\perp} = 35$ pF, Figure 4	-40°C to +85°C	2			ns
Charge Injection	Q	$V_{GEN} = 0V$; $R_{GEN} = 0\Omega$; $C_L = 1nF$, Figure 5	+25°C		0.2		рС

ELECTRICAL CHARACTERISTICS—Single +5V Supply (continued)

 $(V+=+4.5V \text{ to } +5.5V, V-=0V, V_{IH}=+2V, V_{IL}=+0.8V, T_A=-40^{\circ}C \text{ to } +85^{\circ}C, \text{ unless otherwise noted.}$ Typical values are at $T_A=+25^{\circ}C.$) (Notes 2, 3, 4)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS		
Off-Isolation (Note 8)	V _{ISO}	$f = 0.1MHz$, $R_L = 50\Omega$, $C_L = 5pF$ Figure 6	+25°C		-80		dB		
Crosstalk (Note 9)	Vст	$f = 0.1MHz$, $R_L = 50\Omega$, $C_L = 5pF$ Figure 6	+25°C		-87		dB		
DIGITAL I/O	DIGITAL I/O								
Input Logic-High	V _{IH}			2			V		
Input Logic-Low	V _{IL}					0.8	V		
Input Leakage Current	ILEAKAGE	V _{IN} _ = 0V or V+		-1		+1	μΑ		
SUPPLY									
Positivo Supply Current	1+	V+ = 5.5V; V _{IN} = 0V or V+	+25°C			0.1			
Positive Supply Current	1+	V+ - 3.3V, V N_ = 0V 0 V+	-40°C to +85°C	-1		1	μΑ		

ELECTRICAL CHARACTERISTICS—Dual ±5V Supplies (MAX4691/MAX4692/MAX4693 only)

 $(V+ = +4.5V \text{ to } +5.5V, V- = -4.5V \text{ to } -5.5V, V_{IH} = +2V, V_{IL} = +0.8V, T_A = -40^{\circ}C \text{ to } +85^{\circ}C, \text{ unless otherwise noted.})$ (Notes 2, 3, 4)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	Vx, Vy, Vz, Vx_, Vy_, Vz_		-40°C to +85°C	V-		V+	V
On-Resistance (Note 5)	R _{ON}	$V+ = 4.5V; I_X, I_Y, I_Z = 10mA;$	+25°C		18	25	Ω
On-Hesistance (Note 3)	TION	$V- = -4.5V$; V_{X} , V_{Y} , $V_{Z} = 3.5V$	-40°C to +85°C			30	52
On-Resistance Match Between Channels	ΔRON	V+ = 4.5V; V- = -4.5V; I _X , I _Y , I _Z =	+25°C		2	3	Ω
(Notes 5, 6)	ΔιτΟΝ	10mA; V_{X} , V_{Y} , $V_{Z} = 3.5V$	-40°C to +85°C			4	32
On-Resistance Flatness	Dec 45(01)	$V + = 4.5V; V - = -4.5V; I_X, I_Y, I_Z = 4.5V; V - 2.5V; V - 2.5$	+25°C		2.5	3.5	Ω
(Note 10)	RFLAT(ON)	10mA; V_X , V_Y , $V_Z = 3.5V$, $0V$, $-3.5V$	-40°C to +85°C			4	52
X_ , Y_, Z_ Off-Leakage	lχ_,	V+ = 5.5V; V- = -5.5V; V _X , V _Y , V _Z = +4.5V; V _X , V _Y , V _Z = ±4.5V	+25°C	-1		+1	^
Current (Note 7)	ΙΥ_, Ι <u>Ζ</u> _		-40°C to +85°C	-10		+10	nA
V V 7 Off Lookaga Current	IX (OFF),	V+ = 5.5V; V- = -5.5V; Vx, Vy,	+25°C	-2		+2	
X, Y, Z Off-Leakage Current (Note 7)	ly(OFF), lz(OFF)	V _Z = +4.5V; V _X , V _Y , V _Z = ±4.5V	-40°C to +85°C	-20		+20	nA

ELECTRICAL CHARACTERISTICS—Dual ±5V Supplies (continued) (MAX4691/MAX4692/MAX4693 only)

 $(V+ = +4.5V \text{ to } +5.5V, V- = -4.5V \text{ to } -5.5V, V_{IH} = +2V, V_{IL} = +0.8V, T_A = -40^{\circ}C \text{ to } +85^{\circ}C, \text{ unless otherwise noted.})$ (Notes 2, 3, 4)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
X, Y, Z On-Leakage Current	IX(ON),	V+ = 5.5V; V- = -5.5V; $V_X, V_Y, V_Z = \pm 4.5V;$	+25°C	-2		2	^
(Note 7)	ly(ON), lz(ON)	V_{X} , V_{Y} , $V_{Z} = \pm 4.5V$, or unconnected	-40°C to +85°C	-20		20	nA
DYNAMIC							
Facility Town On Time		$V_{X}, V_{Y}, V_{Z} = 3V; R_L = 300\Omega,$	+25°C		55	80]
Enable Turn-On Time	ton	C _L = 35pF, Figure 2	-40°C to +85°C			90	ns
Enable Turn-Off Time	toff	$V_{X}, V_{Y}, V_{Z} = 3V; R_L = 300\Omega,$	+25°C		35	50	ns
Lilable fulli-Oil fillie	UFF	C _L = 35pF, Figure 2	-40°C to +85°C			60	113
		V _{X_} , V _{Y_} , V _{Z_} = 0V, 3V;	+25°C		60	90	
Address Transition Time	ttrans	$R_L = 300\Omega$, $C_L = 35pF$, Figure 3	-40°C to +85°C			100	ns
Break-Before-Make	tввм	$V_{X}, V_{Y}, V_{Z} = 3V; R_L = 300\Omega,$ $C_L = 35pF, Figure 4$	+25°C	2	20		no
Dieak-Deiole-Make			-40°C to +85°C	2			ns
Charge Injection	Q	$V_{GEN} = 0V$; R $_{GEN} = 0\Omega$; $C_{L} = 1$ nF, Figure 5	+25°C		1.8		рС
Off-Isolation (Note 8)	V _{ISO}	$f = 0.1MHz$, $R_L = 50\Omega$, $C_L = 5pF$, Figure 6	+25°C		-82		dB
Crosstalk (Note 9)	VCT	$f = 0.1MHz$, $R_L = 50\Omega$, $C_L = 5pF$, Figure 7	+25°C		-84		dB
Total Harmonic Distortion	THD	$f = 20$ Hz to 20 kHz, V_X , V_Y , $V_Z = 5$ Vp-p; $R_L = 600\Omega$,	+25°C		0.02		%
DIGITAL I/O							
Input Logic-High	VIH			2			V
Input Logic-Low	VIL					0.8	V
Input Leakage Current	liN	V_A , V_B , V_C , $V_{\overline{EN}} = 0V$ or $V+$		-1		+1	μΑ
SUPPLY	_		.				
Positive Supply Current	+	V+ = 5.5V; V- = 5.5V;	+25°C			0.1	μΑ
. II Capp., Carron	1	V_A , V_B , V_C , $V_{\overline{EN}} = 0V$ or $V+$	-40°C to +85°C			1	μ, ,

- **Note 2:** The algebraic convention, where the most negative value is a minimum and the most positive value is a maximum, is used in this data sheet.
- **Note 3:** UCSP parts are 100% tested at $T_A = +25$ °C. Limits across the full temperature range are guaranteed by correlation.
- Note 4: QFN and TQFN parts are 100% tested at TA = +85°C. Limits across the full temperature range are guaranteed by correlation.
- Note 5: UCSP RON and RON match are guaranteed by design.
- **Note 6:** $\Delta Ron = Ron(MAX) Ron(MIN)$.
- Note 7: Leakage parameters are guaranteed by design.
- **Note 8:** Off-isolation = $20\log_{10} (V_{W,X,Y,Z} / V_{W_{-},X_{-},Y_{-},Z_{-}}), V_{W,X,Y,Z} = \text{output}, V_{W_{-},X_{-},Y_{-},Z_{-}} = \text{input to off switch}.$
- Note 9: Between any two switches.
- **Note 10:** Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

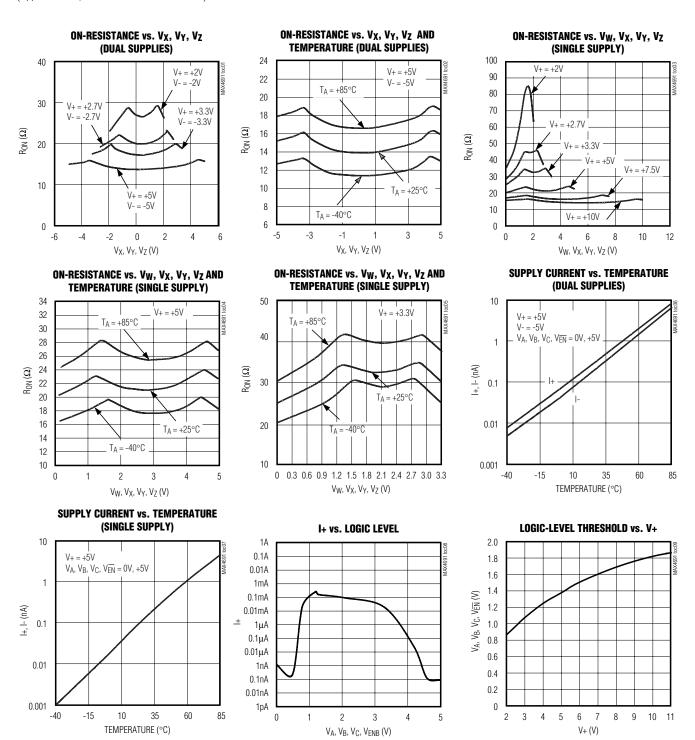
6 __________/N/XI/M

7

Low-Voltage 8:1 Mux/Dual 4:1 Mux/Triple SPDT/ Quad SPDT in UCSP Package

Typical Operating Characteristics

 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$

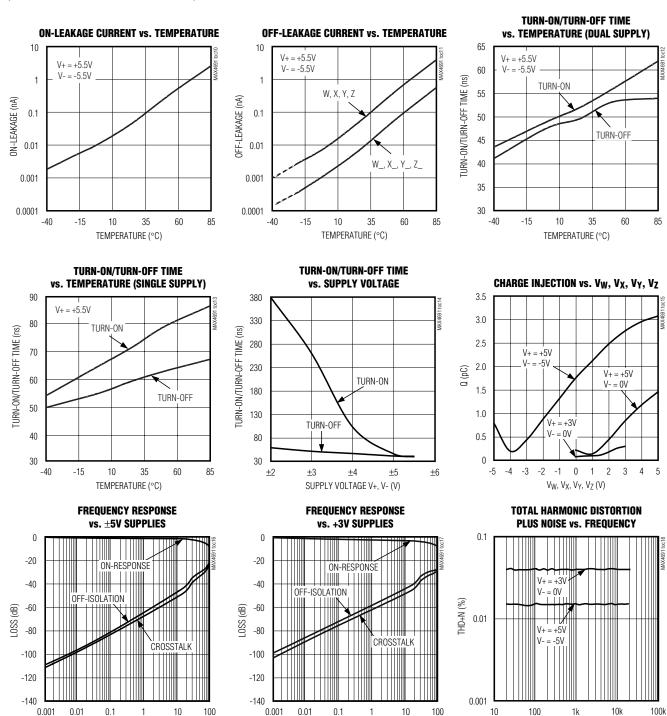


MIXIM

Typical Operating Characteristics (continued)

FREQUENCY (Hz)

 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$



FREQUENCY (MHz)

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FREQUENCY (MHz)

Pin Description

MAX4691

P	IN		
UCSP	QFN-EP/ TQFN-EP	NAME	FUNCTION
A4, B4, C4, D4, A1, B1, C1, D1	16, 1, 3, 4, 12, 11, 9, 8	X0-X7	Analog Switch Inputs 0-7
A2	13	Χ	Analog Switch Common
D3, D2, A3	5, 7, 15	A, B, C	Digital Address Inputs
B2	14	V-	Negative Analog Supply Voltage Input. Connect V- to GND for single-supply operation.
В3	2	GND	Ground. Connect to digital ground. (Analog signals have no ground reference; they are limited to V+ and V)
C2	10	ĒN	Digital Enable Input. Normally connect $\overline{\text{EN}}$ to GND. $\overline{\text{EN}}$ can be driven to logic high to set all switches off.
С3	6	V+	Positive Analog and Digital Supply Voltage Input
_	_	EP	Exposed Pad (QFN and TQFN only). Connect EP to V+.

MAX4692

Р	IN		
UCSP	QFN-EP/ TQFN-EP	NAME	FUNCTION
A1, B1, C1, D1	12, 11, 9, 8	X0-X3	Analog Switch "X" Inputs 0-3
A4, B4, C4, D4	16, 1, 3, 4	Y0-Y3	Analog Switch "Y" Inputs 0-3
A2	13	Χ	Analog Switch "X" Common
А3	15	Υ	Analog Switch "Y" Common
D3, D2	5, 7	A, B	Digital Address Inputs for both "X" and "Y" Analog Switches
B2	14	V-	Negative Analog Supply Voltage Input. Connect V- to GND for single-supply
В3	2	GND	Ground. Connect to digital ground. (Analog signals have no ground reference; they are limited to V+ and V)
C2	10	ĒN	Digital Enable Input. Normally connect $\overline{\text{EN}}$ to GND. $\overline{\text{EN}}$ can be driven to logic high to set all switches off.
C3	6	V+	Positive Analog and Digital Supply Voltage Input
_	_	EP	Exposed Pad (QFN and TQFN only). Connect EP to V+.



_Pin Description (continued)

MAX4693

PIN			
UCSP	QFN-EP/ NAME TQFN-EP		FUNCTION
A1	12	X0	Analog Switch "X" Normally Closed Input
B1	11	X1	Analog Switch "X" Normally Open Input
A4	16	Y0	Analog Switch "Y" Normally Closed Input
B4	1	Y1	Analog Switch "Y" Normally Open Input
D1	8	Z0	Analog Switch "Z" Normally Closed Input
C1	9	Z1	Analog Switch "Z" Normally Open Input
A2	13	Х	Analog Switch "X" Common
A3	15	Υ	Analog Switch "Y" Common
D2	7	Z	Analog Switch "Z" Common
C4	3	А	Analog Switch "X" Digital Control Input
D4	4	В	Analog Switch "Y" Digital Control Input
D3	5	С	Analog Switch "Z" Digital Control Input
B2	14	V-	Negative Analog Supply Voltage Input. Connect V- to GND for single-supply operation.
В3	2	GND	Ground. Connect GND to digital ground. (Analog signals have no ground reference; they are limited to V+ and V)
C2	10	ĒN	Digital Enable Input. Normally connect $\overline{\text{EN}}$ to GND. $\overline{\text{EN}}$ can be driven to logic high to set all switches off.
C3	6	V+	Positive Analog and Digital Supply Voltage Input
_	_	EP	Exposed Pad (QFN and TQFN only). Connect EP to V+.

Pin Description (continued)

MAX4694

F	PIN		
USCP	QFN-EP/ TQFN-EP	NAME	FUNCTION
D4	4	W0	Analog Switch "W" Normally Closed Input
C4	3	W1	Analog Switch "W" Normally Open Input
A1	12	X0	Analog Switch "X" Normally Closed Input
B1	11	X1	Analog Switch "X" Normally Open Input
A4	16	Y0	Analog Switch "Y" Normally Closed Input
B4	1	Y1	Analog Switch "Y" Normally Open Input
D1	8	Z0	Analog Switch "Z" Normally Closed Input
C1	9	Z1	Analog Switch "Z" Normally Open Input
D3	5	W	Analog Switch "W" Common
A2	13	Х	Analog Switch "X" Common
А3	15	Y	Analog Switch "Y" Common
D2	7	Z	Analog Switch "Z" Common
B2	14	GND	Ground
В3	2	А	Analog Switch "W" and "Y" Digital Control Input
C2	10	В	Analog Switch "X" and "Z" Digital Control Input
C3	6	V+	Positive Analog and Digital Supply Voltage Input
_	_	EP	Exposed Pad (QFN and TQFN only). Connect EP to V+.

Table 1. Truth Table/Switch Programming

EN ¹	ADDRESS BITS			ON SWITCHES				
	C ²	В	Α	MAX4691	MAX4692	MAX4693	MAX4694	
1	Χ	Χ	Х	All switches open	All switches open	All switches open	_	
0	0	0	0	X-X0	X-X0, Y-Y0	X-X0, Y-Y0, Z-Z0	W-W0, X-X0, Y-Y0, Z-Z0	
0	0	0	1	X-X1	X-X1, Y-Y1	X-X1, Y-Y0, Z-Z0	W-W1, X-X0, Y-Y1, Z-Z0	
0	0	1	0	X-X2	X-X2, Y-Y2	X-X0, Y-Y1, Z-Z0	W-W0, X-X1, Y-Y0, Z-Z1	
0	0	1	1	X-X3	X-X3, Y-Y3	X-X1, Y-Y1, Z-Z0	W-W1, X-X1, Y-Y1, Z-Z1	
0	1	0	0	X-X4	X-X0, Y-Y0	X-X0, Y-Y0, Z-Z1	W-W0, X-X0, Y-Y0, Z-Z0	
0	1	0	1	X-X5	X-X1, Y-Y1	X-X1, Y-Y0, Z-Z1	W-W1, X-X0, Y-Y1, Z-Z0	
0	1	1	0	X-X6	X-X2, Y-Y2	X-X0, Y-Y1, Z-Z1	W-W0, X-X1, Y-Y0, Z-Z1	
0	1	1	1	X-X7	X-X3, Y-Y3	X-X1, Y-Y1, Z-Z1	W-W1, X-X1, Y-Y1, Z-Z1	

X = Don't care

Detailed Description

The MAX4691–MAX4694 are low-voltage CMOS analog ICs configured as an 8-channel multiplexer (MAX4691), two 4-channel multiplexers (MAX4692), three SPDT switches (MAX4693), and four SPDT switches (MAX4694). All switches are bidirectional.

The MAX4691/MAX4692/MAX4693 operate from either a single +2V to +11V power supply or dual ±2V to ±5.5V power supplies. When operating from ±5V supplies they offer 25Ω on-resistance (RoN), 3.5Ω max RoN flatness, and 3Ω max matching between channels. The MAX4694 operates from a single +2V to +11V supply. Each switch has rail-to-rail signal handling, fast switching times of toN = 80ns, toff = 50ns, and a low 1nA leakage current.

All digital inputs are 1.8V logic-compatible when operating from a +3V supply and TTL-compatible when operating from a +5V supply.

Digital Inputs

The MAX4691 and MAX4692 include address pins that allow control of the multiplexers. For the MAX4691, pins

A, B, C determine which switch is closed. The two 4-1 muxes in the MAX4692 are controlled by the same address pins (A and B). (Table 1)

The MAX4693 and MAX4694 offer SPDT switches in triple and quadruple packages. In the MAX4693, each switch has a unique control input. The MAX4694 has two digital control inputs: A (for switches "W" and "Y") and B (for switches "X" and "Z"). (Table 1)

Applications Information

Power-Supply Considerations

Overview

The MAX4691–MAX4694 construction is typical of most CMOS analog switches. V+ and V-* are used to drive the internal CMOS switches and set the limits of the analog voltage on any switch. Reverse ESD-protection diodes are internally connected between each analog signal pin and both V+ and V-. If any analog signal exceeds V+ or V-, one of these diodes will conduct.

*V- is found only on the MAX4691/MAX4692/MAX4693.

12 /**U** /**X** / **U**

^{1.} EN is not present on the MAX4694.

^{2.} C is not present on the MAX4692 and MAX4694.

During normal operation, these (and other) reverse-biased ESD diodes leak, forming the only current drawn from V+ or V-.

Virtually all the analog leakage current comes from the ESD diodes. Although the ESD diodes on a given signal pin are identical, and therefore fairly well balanced, they are reverse biased differently. Each is biased by either V+ or V- and the analog signal. This means their leakages will vary as the signal varies. The *difference* in the two diode leakages to the V+ and V- pins constitutes the analog signal path leakage current. All analog leakage current flows between each pin and one of the supply terminals, not to the other switch terminal. This is why both sides of a given switch can show leakage currents of either the same or opposite polarity.

V+ and GND power the internal logic and logic-level translators, and set both the input and output logic limits. The logic-level translators convert the logic levels into switched V+ and V- signals to drive the gates of the analog signals. This drive signal is the only connection between the logic supplies (and signals) and the analog supplies. V+ and V- have ESD-protection diodes on GND.

Bipolar Supplies

The MAX4691/MAX4692/MAX4693 operate with bipolar supplies between ±2V and ±5.5V. The V+ and V- supplies need not be symmetrical, but their difference cannot exceed the absolute maximum rating of +12V.

Single Supply

These devices operate from a single supply between +2V and +11V when V- is connected to GND. All of the bipolar precautions must be observed. At room temperature, they operate with a single supply at near or below +2V, although as supply voltage decreases, switch on-resistance and switching times become very high.

Always bypass supplies with a 0.1µF capacitor.

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, then V-, followed by the logic inputs and by W, X, Y, Z. If power-supply sequencing is not possible, add two small signal diodes (D1, D2) in series with the supply pins for overvoltage protection (Figure 1).

Adding diodes reduces the analog signal range to one diode drop below V+ and one diode drop above V-, but does not affect the devices' low switch resistance and low leakage characteristics. Device operation is

unchanged, and the difference between V+ and V-should not exceed 12V. These protection diodes are not recommended when using a single supply if signal levels must extend to ground.

UCSP Reliability

The chip-scale package (UCSP) represents a unique package that greatly reduces board space compared to other packages. UCSP reliability is integrally linked to the user's assembly methods, circuit board material, and usage environment. The user should closely review these areas when considering a UCSP. Performance through Operating Life Test and Moisture Resistance is equal to conventional package technology as it is primarily determined by the wafer-fabrication process. However, this form factor may not perform equally to a packaged product through traditional mechanical reliability tests.

Mechanical stress performance is a greater consideration for a UCSP. UCSP solder joint contact integrity must be considered since the package is attached through direct solder contact to the user's PC board. Testing done to characterize the UCSP reliability performance shows that it is capable of performing reliably through environmental stresses. Results of environmental stress tests and additional usage data and recommendations are detailed in the UCSP application note, which can be found on Maxim's website, at www.maxim-ic.com.

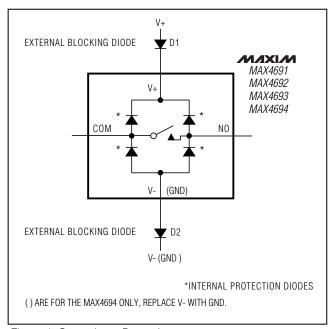


Figure 1. Overvoltage Protection

Test Circuits/Timing Diagrams

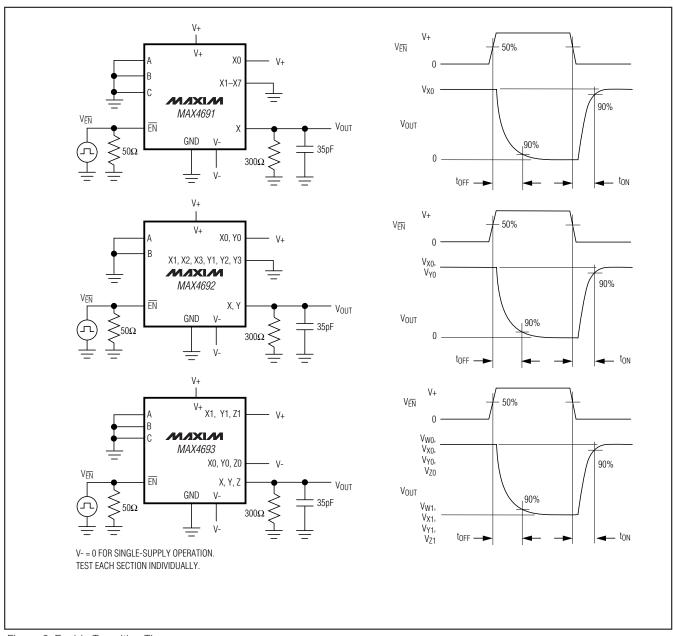


Figure 2. Enable Transition Time

Test Circuits/Timing Diagrams (continued)

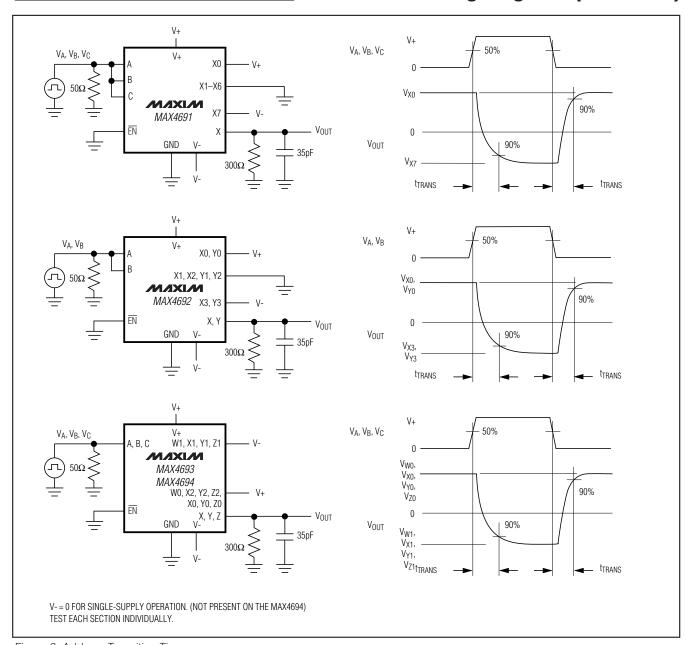


Figure 3. Address Transition Time

Test Circuits/Timing Diagrams (continued)

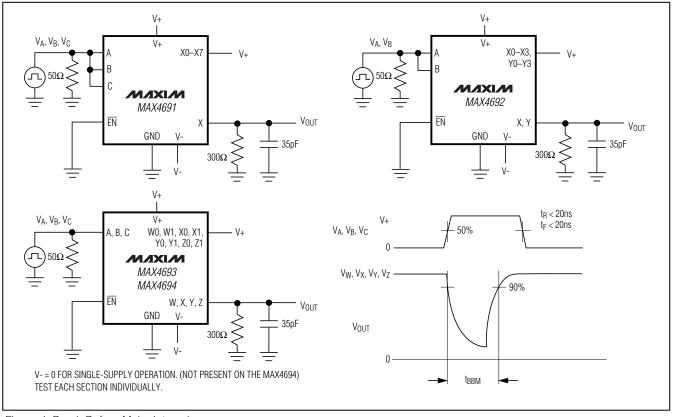


Figure 4. Break-Before-Make Interval

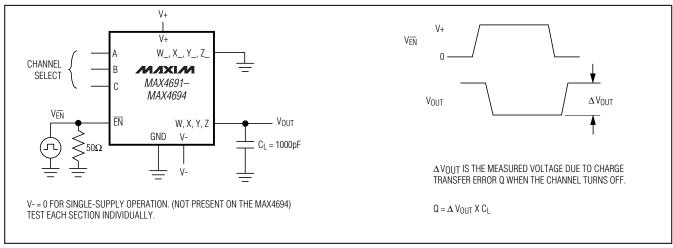


Figure 5. Charge Injection

Test Circuits/Timing Diagrams (continued)

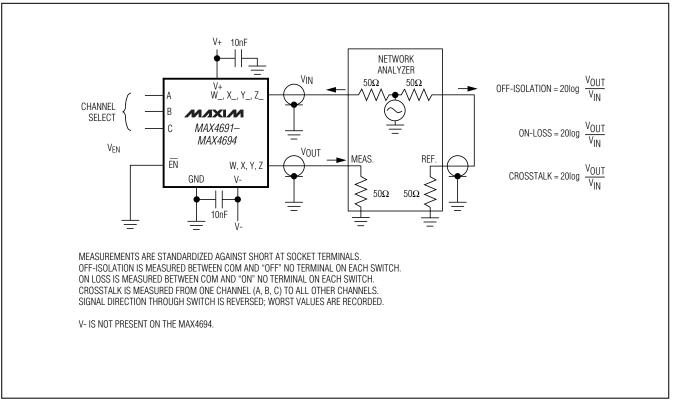


Figure 6. Off-Isolation, On-Loss, and Crosstalk

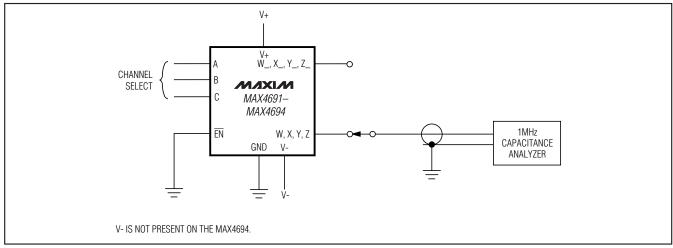
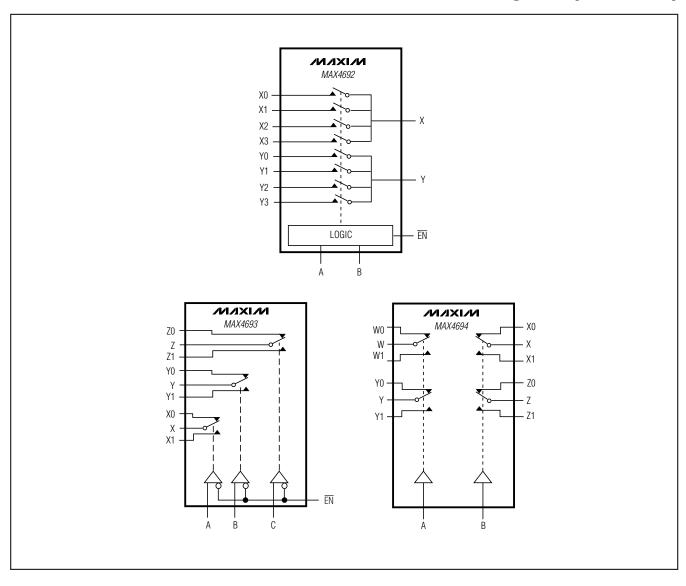


Figure 7. Capacitance

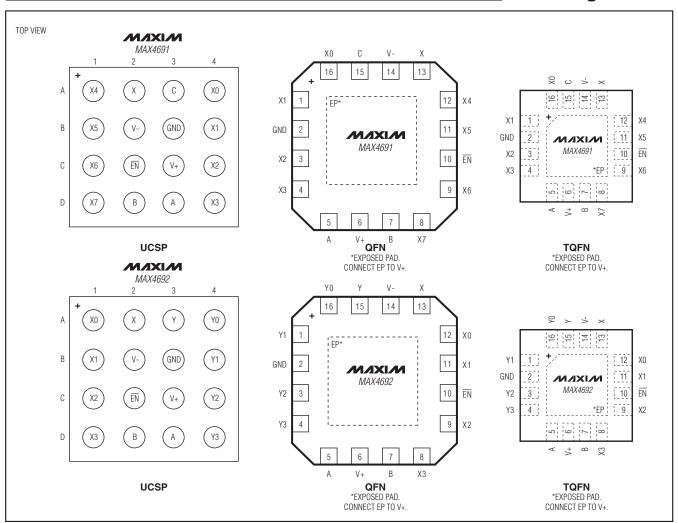
Functional Diagrams (continued)



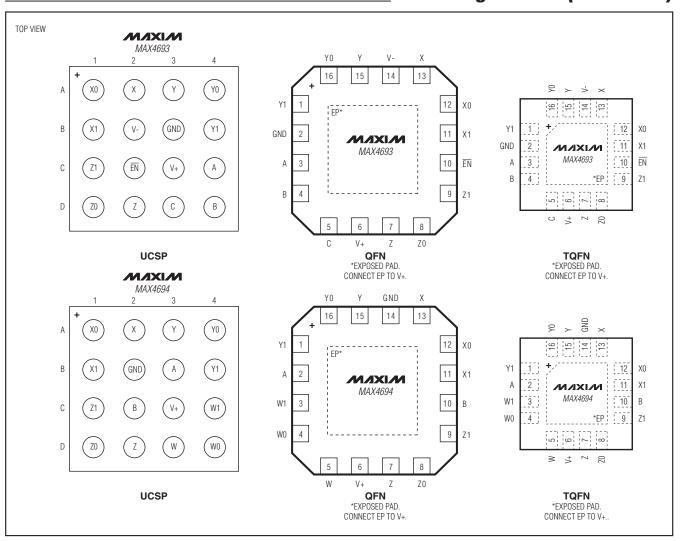
_Chip Information

PROCESS: BICMOS

Pin Configurations



Pin Configurations (continued)



Package Information

For the latest package outline information and land patterns (footprints), go to www.maxim-ic.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
16 UCSP	B16+1	<u>21-0101</u>	Refer to Application Note 1891
16 QFN-EP	G1644+1	<u>21-0106</u>	<u>90-0216</u>
16 TQFN-EP	T1644+4	21-0139	<u>90-0070</u>

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	1/01	Initial release	_
1	7/01	Added UCSP Package	_
2	2/03	Removed statement in Features section with UCSP now qualified	_
3	12/06	Exposed Paddle Connection information edited, style changes	1, 9, 10, 11, 19, 21, 22
4	8/08	Added part numbers, package diagram, and TQFN packaging	1–26
5	3/09	Added lead-free packaging, edited <i>Pin Description</i> , revised <i>Chip Information</i> , changed "floating" to "unconnected," style changes	1–6, 9, 10, 11, 18–21
6	1/12	Updated Absolute Maximum Ratings and Pin Description sections	2, 9, 10

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